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5-V Dual TTL-to-Differential PECL Translator

FEATURES

- 1.1-ns (max) Propagation Delay
- Operating Range: V_{CC} = 4.2V to 5.7V with GND = 0 V
- < 50-ps (typ) Output-to-Output Skew
- Built-In Temperature Compensation
- Drop-In Compatible to the MC10ELT22, MC100ELT22

APPLICATIONS

- Data and Clock Transmission Over Backplane
- Signaling Level Conversion for Clock or Data

DESCRIPTION

The SN65ELT22 is a dual TTL-to-differential PECL translator. It operates on +5-V supply and ground only. The output is undetermined when the inputs are left floating. The low output skew makes the device an ideal solution for clock or data signal translation.

The SN65ELT22 is housed in an industry standard SOIC-8 package and is also available in an optional TSSOP-8 package.

PIN ASSIGNMENT

D or DGK PACKAGE (TOP VIEW)

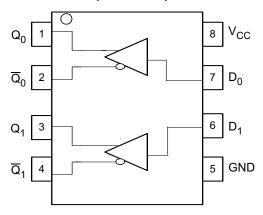


Table 1. Pin Descriptions

PIN	FUNCTION
D ₀ , D ₁	TTL inputs
$Q_0, \overline{Q}_0, Q_1, \overline{Q}_1$	PECL outputs
V _{CC}	Positive supply
GND	Ground

ORDERING INFORMATION(1)

PART NUMBER	PART MARKING	PACKAGE	LEAD FINISH
SN65ELT22D	SN65ELT22	SOIC	NiPdAu
SN65ELT22DGK	SN65ELT22	SOIC-TSSOP	NiPdAu

(1) Leaded device options are not initially available; contact a sales representative for further details



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS(1)

PARAMETER	CONDITIONS	VALUE	UNIT
Absolute PECL mode supply voltage, V _{CC}	GND = 0 V	6	V
Input voltage, V _{IN}	GND = 0 V	GND + 0.025 < V _{IN} < V _{CC} - 0.025	V
Output ourrent	Continuous	50	A
Output current	Surge	100	mA
Operating temperature range		-40 to 85	°C
Storage temperature range	-65 to 150	°C	

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

POWER DISSIPATION RATINGS

PACKAGE	CIRCUIT BOARD MODEL	POWER RATING T _A < 25°C (mW)	THERMAL RESISTANCE, JUNCTION-TO-AMBIENT NO AIRFLOW	DERATING FACTOR T _A > 25°C (mW/°C)	POWER RATING T _A = 85°C (mW)
SOIC	Low-K	719	139	7	288
SOIC	High-K	840	119	8	336
COIC TECOD	Low-K	469	213	5	188
SOIC-TSSOP	High-K	527	189	5	211

THERMAL CHARACTERISTICS

	PARAMET	rer .	MIN	TYP	MAX	UNIT		
0	lunction to board thermal registeres	SOIC		79	°C/W			
θ_{JB}	Junction-to-board thermal resistance	SOIC-TSSOP		C/VV				
0	lunction to cope thermal registeres	SOIC		98		°C/M		
θ_{JC}	Junction-to-case thermal resistance	SOIC-TSSOP		74		°C/W		

KEY ATTRIBUTES

CHARACTERISTICS		VALUE
Moisture sensitivity level		Level 1
Flammability rating (oxygen index: 28 to	34)	UL 94 V-0 at 0.125 in
	Human body model	4 kV
Electrostatic discharge	Charge device model	2 kV
	Machine model	200 V
Meets or exceeds JEDEC Spec EIA/JES	D78 latchup test	

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PECL DC CHARACTERISTICS

At $V_{CC} = 5.0 \text{ V}$, GND = 0.0 V (unless otherwise noted)⁽¹⁾⁽²⁾

PARAMETER		TEST CONDITIONS	T _A = -40°C			T _A = 25°C			T _A = 85°C			UNIT
F/	PARAIVIETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
I _{CC}	Power supply current			17.3	20		18.2	20		19.4	22	mA
V _{OH}	High-level output voltage	See (3)	3915	3954	4120	3915	3958	4120	3915	3961	4120	mV
V _{OL}	Low-level output voltage	See (3)	3170	3236	3380	3170	3231	3380	3170	3229	3380	mV

- (1) The device meets the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) Input and output parameters vary 1:1 with V_{CC} . V_{CC} can vary +0.7 V /-0.8 V.
- (3) Outputs are terminated through a 50- Ω resistor to $V_{CC} 2.0 \text{ V}$.

TTL DC CHARACTERISTICS

At $V_{CC} = 4.2 \text{ V}$ to 5.7 V, $T_A = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)⁽¹⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
I_{IH}	High-level input current	$V_{IN} = 2.7 \text{ V}, V_{IN} = (V_{CC} - 0.025) \text{ V}$		20	μΑ
I_{IHH}	High-level input current	$V_{IN} = V_{CC}$		20	μΑ
I _{IL}	Low-level input current	V _{IN} = 0.5 V, V _{IN} = (GND + 0.025) V		-200	μΑ
V_{IK}	Input clamp diode voltage	I _{IN} = -18 mA		-1.2	V
V_{IH}	High-level input voltage		2.0	Vcc- 0.025	V
V_{IL}	Low-level input voltage		GND + 0.025	0.8	V

⁽¹⁾ The device meets the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously

AC CHARACTERISTICS

At $V_{CC} = 4.2 \text{ V}$ to 5.7 V, GND = 0.0 V (unless otherwise noted)⁽¹⁾

	PARAMETER	TEST CONDITIONS	$T_A = -40^{\circ}C$			T _A = 25°C			T _A = 85°C			UNIT
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
f _{MAX}	Max switching frequency ⁽²⁾ , see Figure 5			500			490			470		MHz
t _{PLH}	Propagation delay time	1.5 V to 50%	0.6	0.83	1.1	0.6	0.84	1.1	0.6	0.85	1.1	no
t _{PHL}	Propagation delay time	1.5 V to 50%	0.5		0.9	0.5		0.9	0.5		0.9	ns
	Within device skew	See ⁽³⁾		25	90		25	90		25	90	20
t _{SKEW}	Device-to-device skew	See (4)		25	100		25	100		25	100	ps
t _{JITTER}	Random clock jitter (RMS)				0.5			0.5			0.5	ps
t _r /t _f	Output rise/fall times	Q (20%–80%)	0.7		1.1	0.7		1.1	0.7		1.1	ns

- (1) The device meets the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) Maximum switching frequency measured at output amplitude of 300 mV_{pp}.
- (3) Measured between outputs under the identical transitions and conditions on any one device.
- (4) Device-to-device skew for identical transitions at identical V_{CC} levels.

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Typical Termination for Output Driver

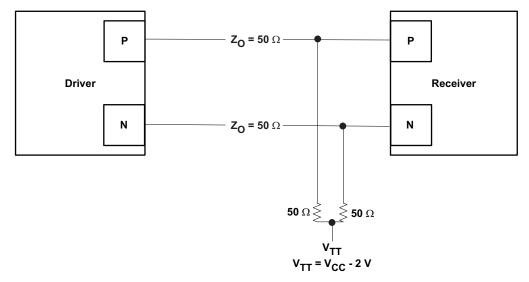


Figure 1. Typical Termination for Driver

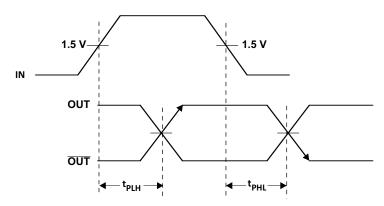


Figure 2. Output Propagation Delay

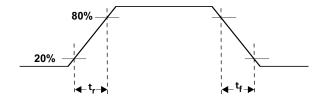


Figure 3. Output Rise and Fall Times

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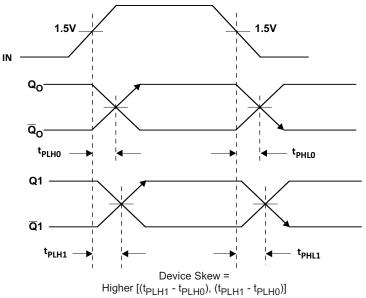


Figure 4. Device Skew

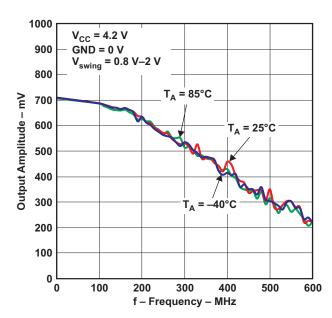


Figure 5. Output Amplitude vs. Frequency

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN65ELT22D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ELT22
SN65ELT22D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ELT22
SN65ELT22DGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIPI
SN65ELT22DGK.B	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIPI
SN65ELT22DGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIPI
SN65ELT22DGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIPI
SN65ELT22DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ELT22
SN65ELT22DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ELT22

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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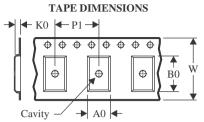
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

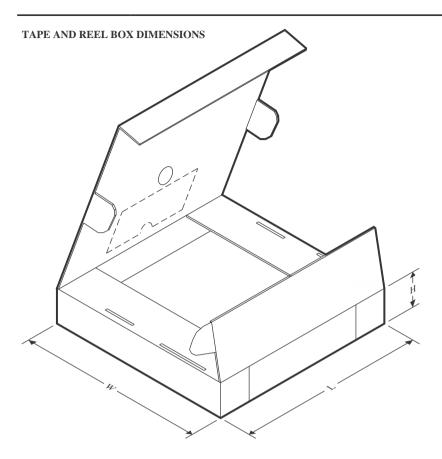


*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65ELT22DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
SN65ELT22DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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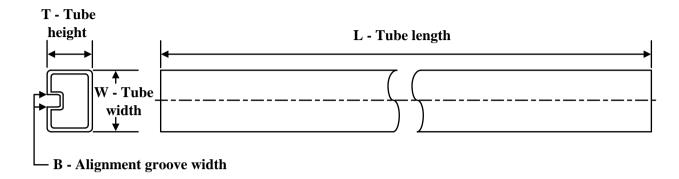
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65ELT22DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
SN65ELT22DR	SOIC	D	8	2500	353.0	353.0	32.0

PACKAGE MATERIALS INFORMATION

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TUBE

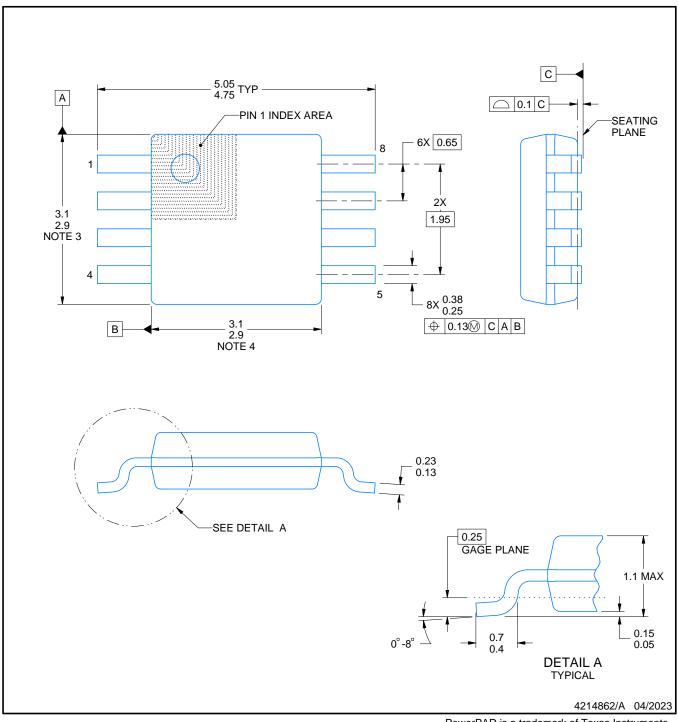


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65ELT22D	D	SOIC	8	75	506.6	8	3940	4.32
SN65ELT22D.B	D	SOIC	8	75	506.6	8	3940	4.32
SN65ELT22DGK	DGK	VSSOP	8	80	330.2	6.6	3005	1.88
SN65ELT22DGK.B	DGK	VSSOP	8	80	330.2	6.6	3005	1.88



SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

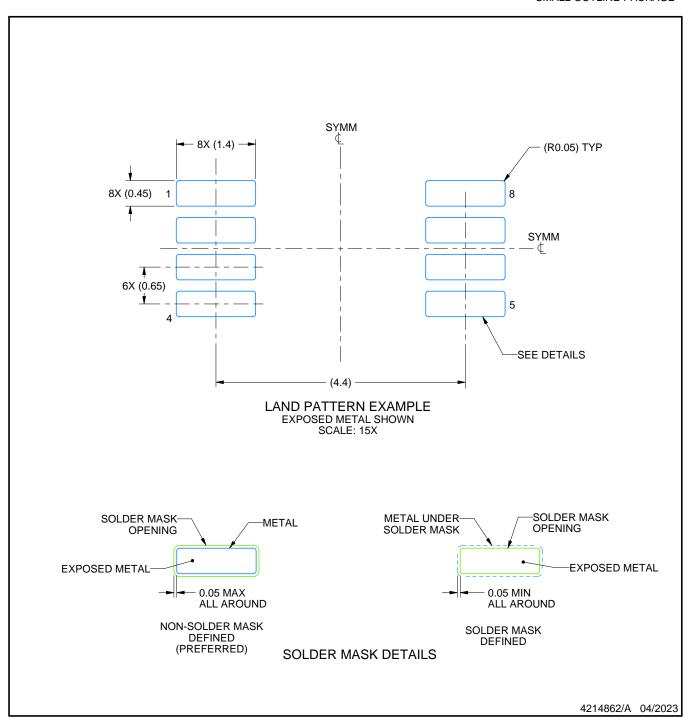
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE

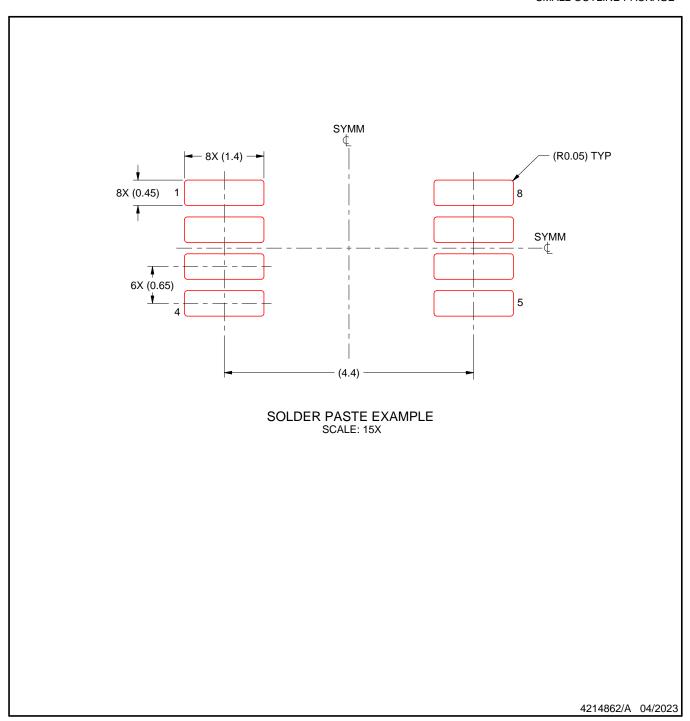


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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